

Soft Phonon Modes Lead to Suppressed Thermal Conductivity in Ag-Based Chalcopyrites under High Pressure

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Table S1. Calculated lattice constants compared with experimental values.¹

	Pressure	This work		Experiment	
		<i>a</i> (Å)	<i>c</i> (Å)	<i>a</i> (Å)	<i>c</i> (Å)
AgAlS ₂	0 GPa	5.63	10.44	5.69	10.24
	3 GPa	5.57	10.28		
AgAlSe ₂	0 GPa	5.91	11.03	5.95	10.71
	3 GPa	5.84	10.82		
AgAlTe ₂	0 GPa	6.28	12.12	6.29	11.83
	3 GPa	6.18	11.88		
AgGaS ₂	0 GPa	5.65	10.49	5.74	10.27
	3 GPa	5.59	10.30		
AgGaSe ₂	0 GPa	5.91	11.10	5.97	10.87
	3 GPa	5.85	10.87		
AgGaTe ₂	0 GPa	6.27	12.13	6.29	11.95
	3 GPa	6.16	11.88		
AgInS ₂	0 GPa	5.80	11.33	5.81	11.16
	3 GPa	5.72	11.16		
AgInSe ₂	0 GPa	6.06	11.89	6.09	11.69
	3 GPa	5.97	11.67		
AgInTe ₂	0 GPa	6.43	12.77	6.44	12.634
	3 GPa	6.31	12.52		

Table S2. Calculated bond lengths of Ag-Y and X-Y, and type I and II bond angles of Y-Ag-Y, Y-X-Y, and Ag-Y-X.

	Pressure	Bond length				Bond angle			
		Ag-Y	X-Y	Y-Ag-Y	Y-Ag-Y	Y-X-Y	Y-X-Y	Ag-Y-X	Ag-Y-X
		(Å)	(Å)	(I)	(II)	(I)	(II)	(I)	(II)
AgAlS ₂	0 GPa	2.51	2.26	117.29°	105.71°	109.49°	109.46°	112.91°	107.01°
	3 GPa	2.47	2.24	117.40°	105.66°	109.94°	109.24°	113.22°	106.92°
AgAlSe ₂	0 GPa	2.61	2.40	116.20°	106.21°	109.95°	109.23°	112.77°	107.36°
	3 GPa	2.57	2.37	116.48°	106.08°	110.50°	108.96°	113.21°	107.18°
AgAlTe ₂	0 GPa	2.75	2.63	113.03°	107.72°	109.79°	109.31°	111.33°	108.42°
	3 GPa	2.69	2.59	113.12°	107.68°	110.08°	109.17°	111.53°	108.34°
AgGaS ₂	0 GPa	2.50	2.29	116.70°	105.98°	110.07°	109.17°	113.04°	107.17°
	3 GPa	2.46	2.26	116.97°	105.86°	110.62°	108.90°	113.47°	107.00°
AgGaSe ₂	0 GPa	2.60	2.43	115.43°	106.57°	110.21°	109.11°	112.61°	107.59°
	3 GPa	2.56	2.39	115.85°	106.38°	110.83°	108.80°	113.14°	107.35°
AgGaTe ₂	0 GPa	2.73	2.64	112.60°	107.93°	109.79°	109.31°	111.14°	108.55°
	3 GPa	2.68	2.59	112.80°	107.83°	110.09°	109.16°	111.39°	108.43°
AgInS ₂	0 GPa	2.51	2.48	111.18°	108.62°	110.24°	109.09°	110.70°	108.85°
	3 GPa	2.46	2.45	111.06°	108.68°	110.54°	108.94°	110.80°	108.81°
AgInSe ₂	0 GPa	2.60	2.61	110.49°	108.96°	110.58°	108.92°	110.54°	108.94°
	3 GPa	2.56	2.57	110.46°	108.98°	110.90°	108.76°	110.68°	108.87°
AgInTe ₂	0 GPa	2.74	2.81	108.89°	109.76	110.82	108.80	109.83°	109.25°
	3 GPa	2.69	2.76	108.80°	109.81	110.98	108.72	109.86°	109.22°

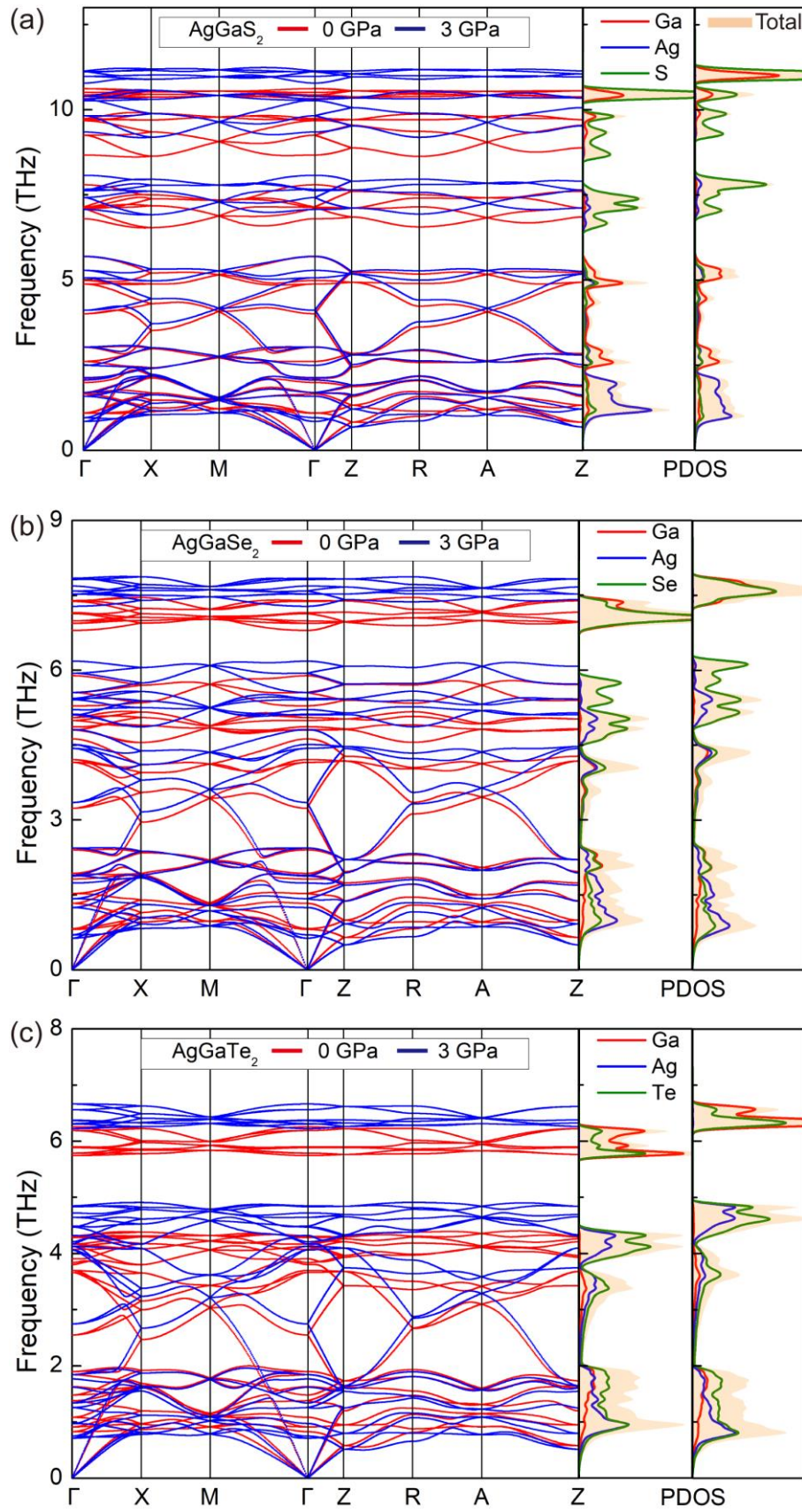


Figure S1. Phonon dispersions and atom-decomposed density of states (PDOS) of (a) AgGaS₂, (b) AgGaSe₂, and (c) AgGaTe₂.

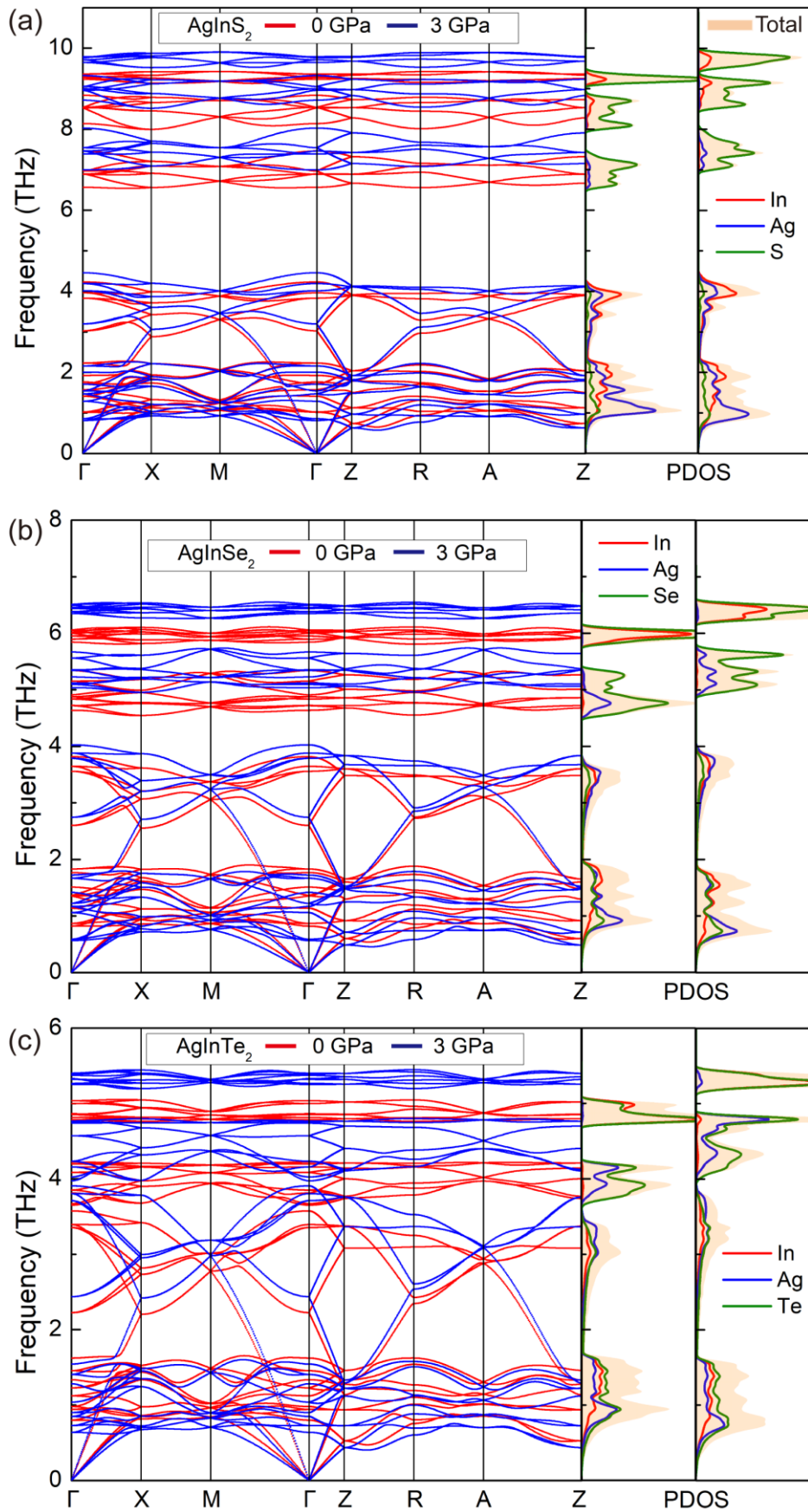


Figure S2. Phonon dispersions and atom-decomposed density of states (PDOS) of (a) AgInS₂, (b) AgInSe₂, and (c) AgInTe₂.

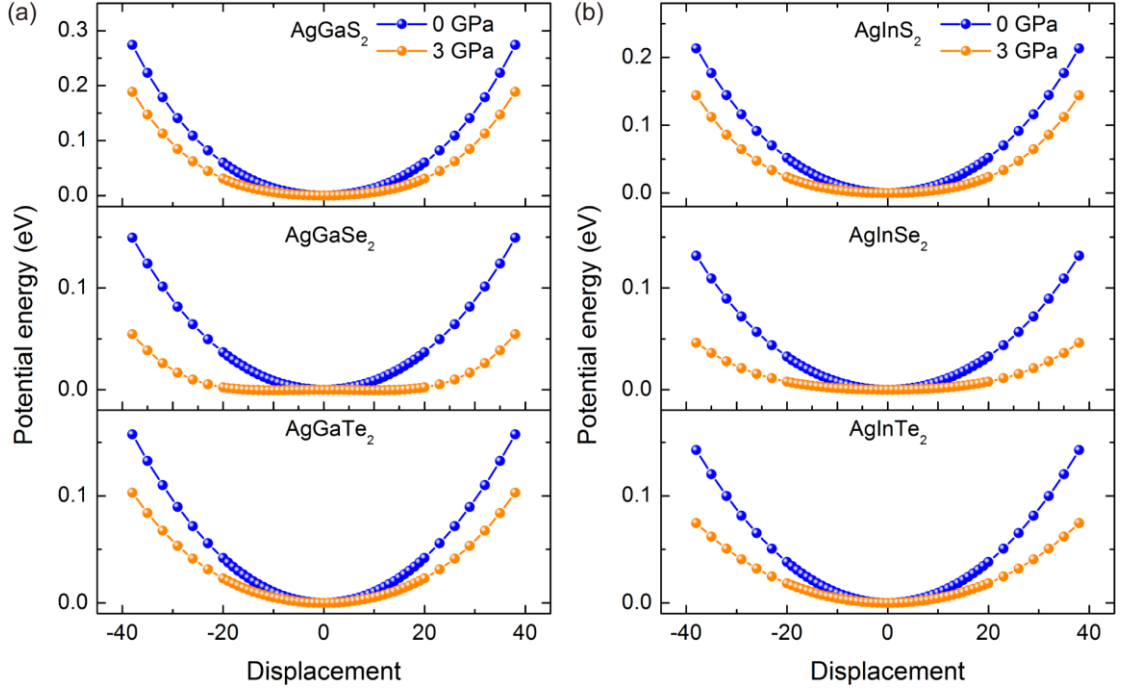


Figure S3. Potential energy variation as a function of displacement for lowest transverse optical mode at the Γ point for (a) AgGaS₂, AgGaSe₂, and AgGaTe₂, and (b) for AgInS₂, AgInSe₂, and AgInTe₂.

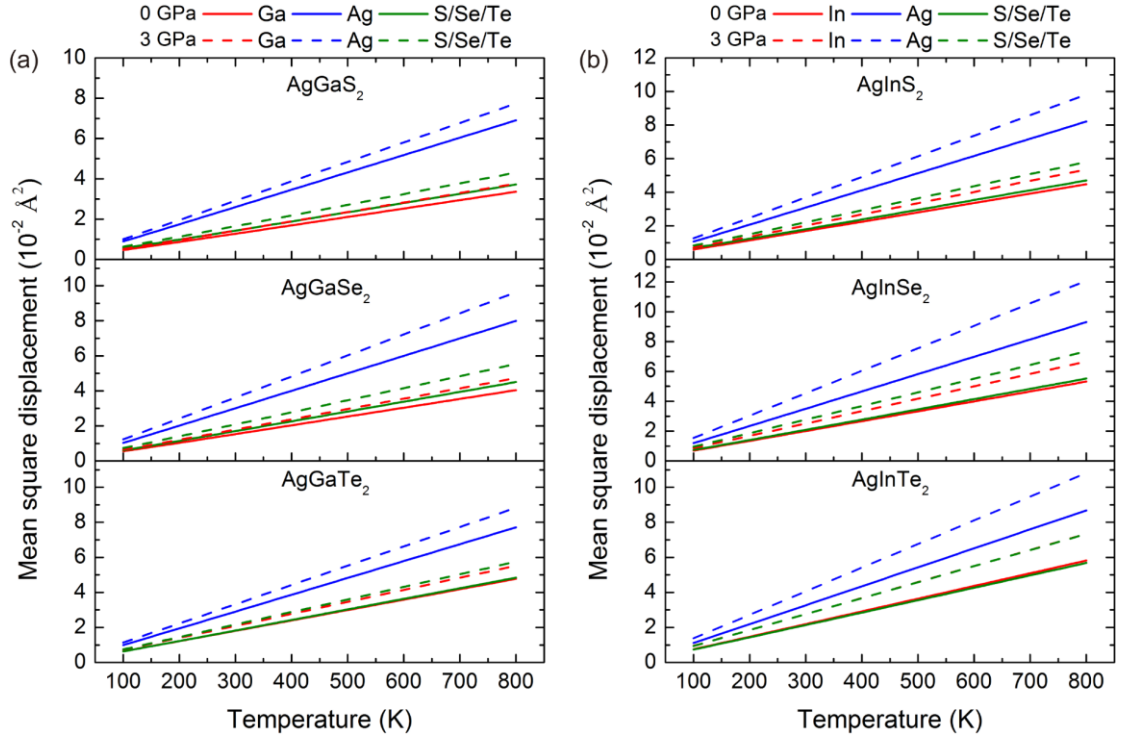


Figure S4. Temperature-dependent mean square displacement for (a) AgGaS₂, AgGaSe₂, and AgGaTe₂, and (b) for AgInS₂, AgInSe₂, and AgInTe₂.

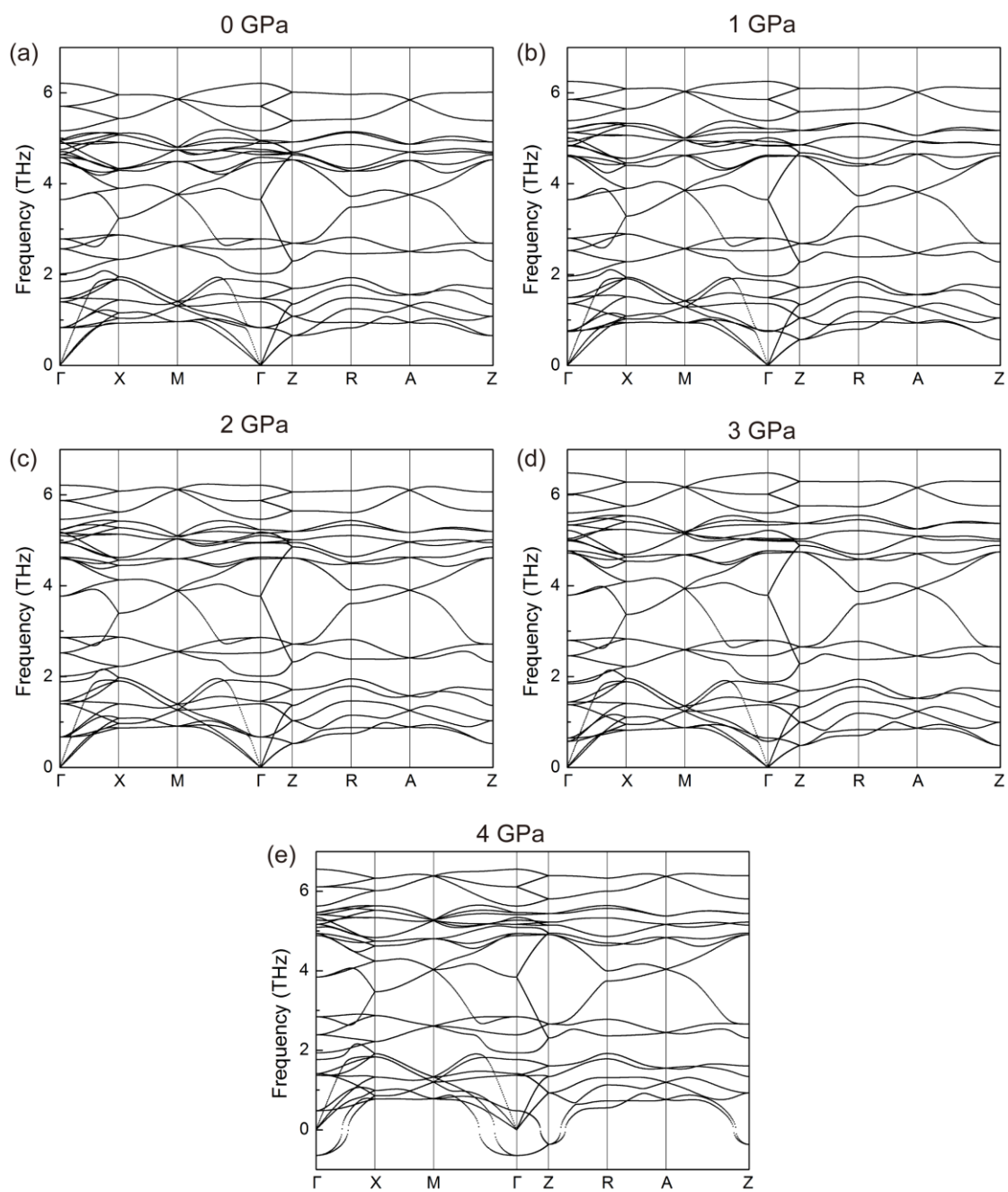


Figure S5. Pressure-dependent phonon dispersions of AgAlSe_2 . (a) 0 GPa, (b) 1 GPa, (c) 2 GPa, (d) 3 GPa, and (e) 4 GPa.

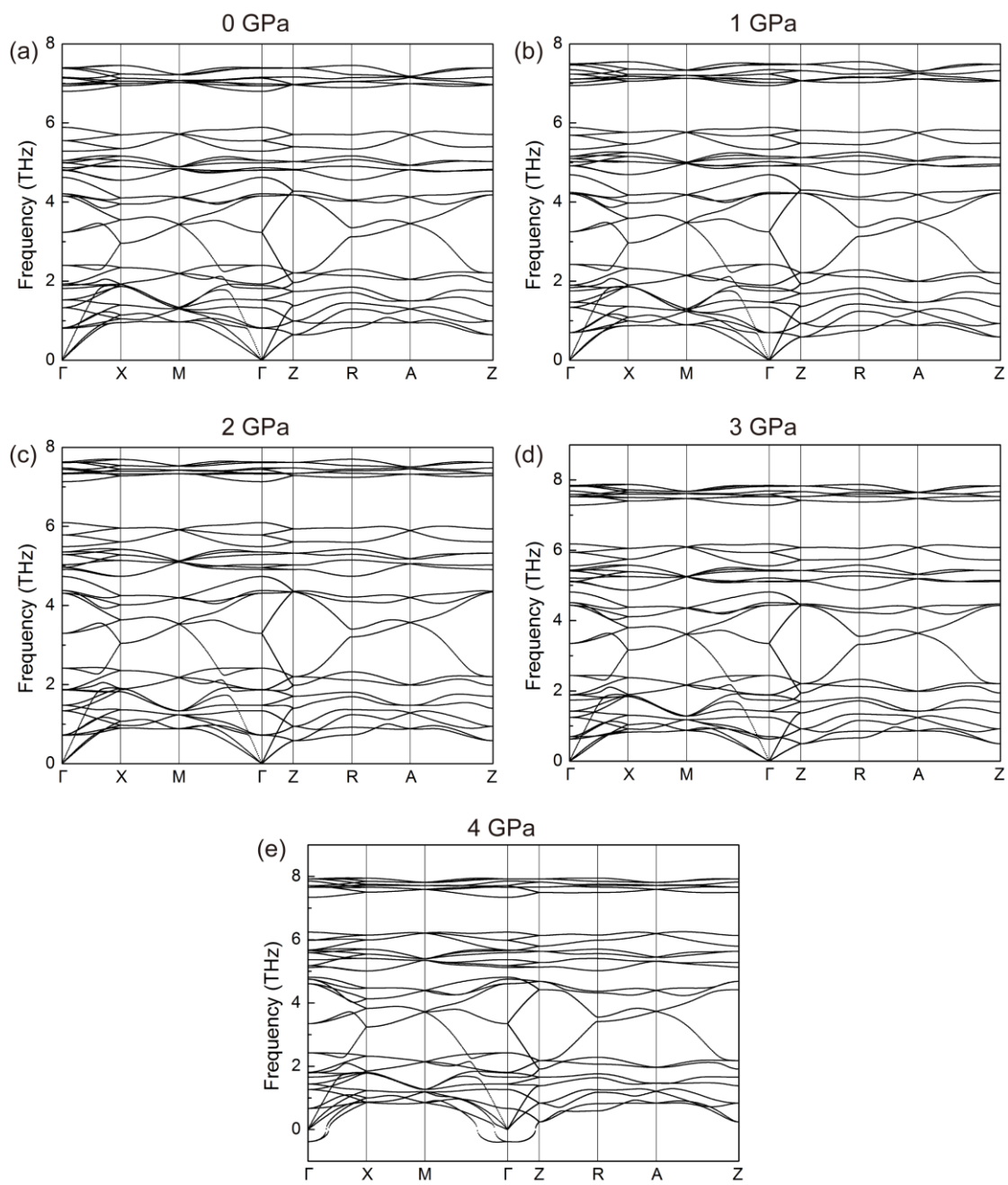


Figure S6. Pressure-dependent phonon dispersions of AgGaSe₂. (a) 0 GPa, (b) 1 GPa, (c) 2 GPa, (d) 3 GPa, and (e) 4 GPa.

Table S3. The calculated thermal conductivity compared with experimental and simulation results. The calculated thermal conductivity is averaged over three directions.

	Thermal conductivity (W/mK)		
	This work	Experiment	Simulation ²
AgAlS ₂	1.71	-	2.03
AgAlSe ₂	1.33	-	0.94
AgAlTe ₂	2.25	-	1.46
AgGaS ₂	2.24	1.4 ³	2.23
AgGaSe ₂	1.33	1.2 ⁴	0.77
AgGaTe ₂	2.60	1.94 ⁵	1.43
AgInS ₂	2.35	-	2.05
AgInSe ₂	1.92	1.1 ⁶	0.89
AgInTe ₂	2.48	2.05 ⁵	1.69

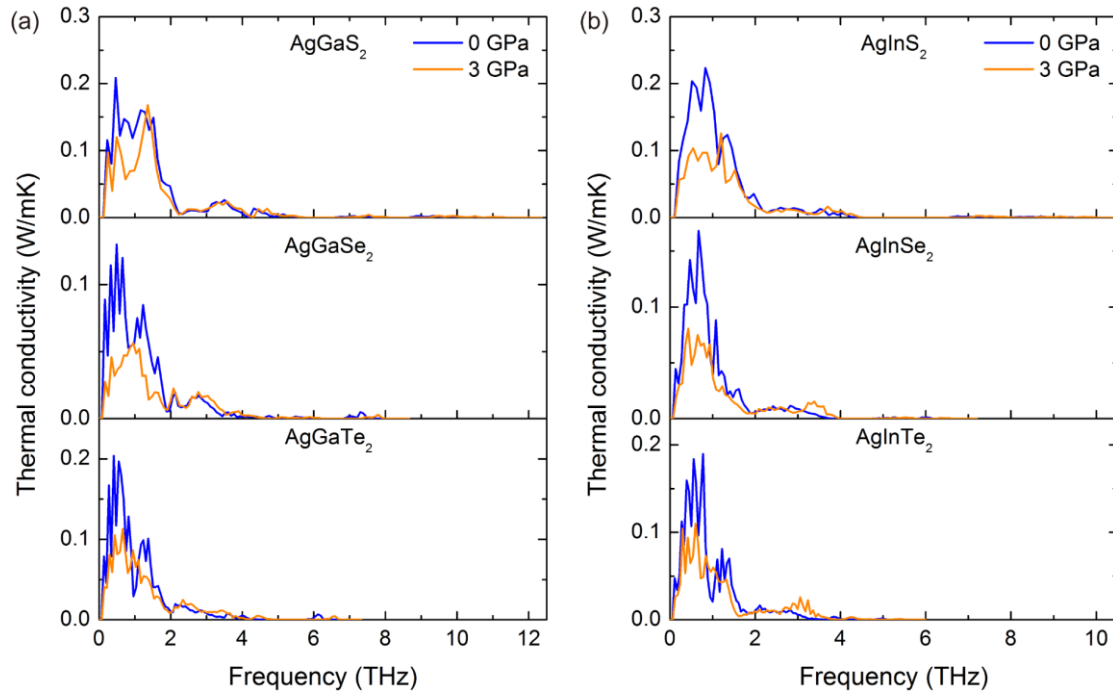


Figure S7. Frequency decomposed thermal conductivity for (a) AgGaS₂, AgGaSe₂, and AgGaTe₂, and (b) for AgInS₂, AgInSe₂, and AgInTe₂ at 0 GPa and 3 GPa.

Table S4. The percentage contribution of phonons in different frequency ranges to thermal conductivity.

	Percentage contribution (%)			
	0-2 THz		0-1 THz	
	0 GPa	3 GPa	0 GPa	3 GPa
AgAlS ₂	77.86	72.73	41.87	34.35
AgAlSe ₂	81.02	70.64	54.31	50.65
AgAlTe ₂	83.73	81.55	59.86	58.81
AgGaS ₂	85.33	79.83	47.97	40.70
AgGaSe ₂	85.46	74.54	53.08	46.94
AgGaTe ₂	88.98	81.65	61.14	58.76
AgInS ₂	90.30	84.91	62.95	53.05
AgInSe ₂	90.41	81.52	70.23	64.65
AgInTe ₂	91.38	82.65	67.91	63.54

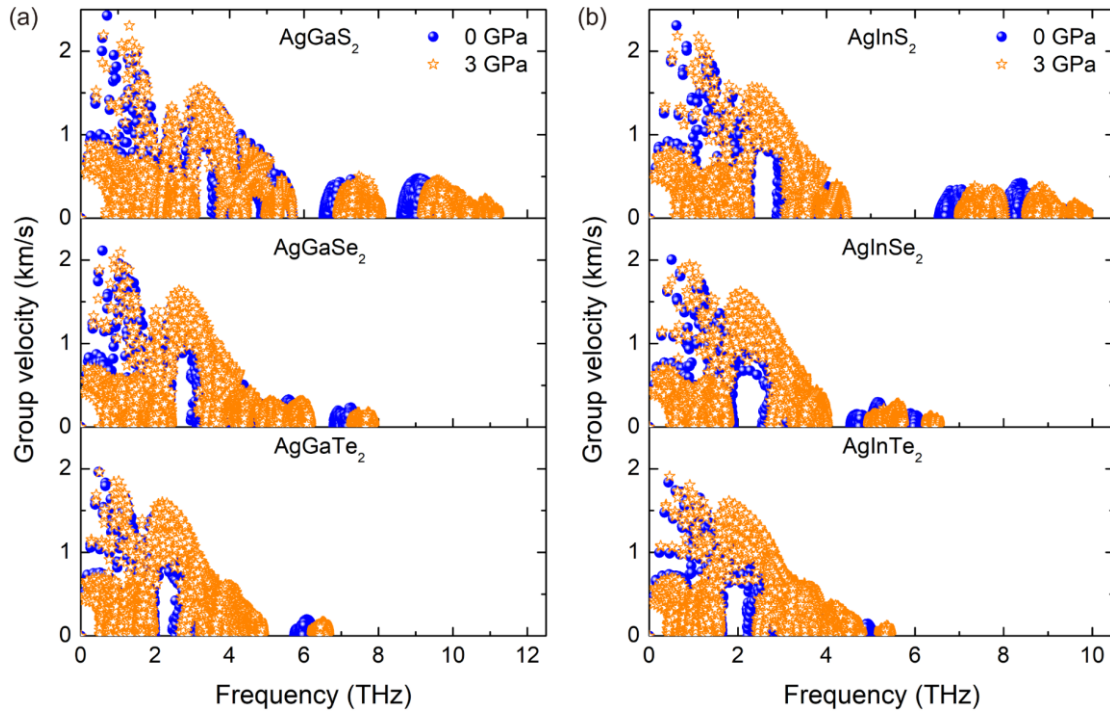


Figure S8. Phonon group velocity for (a) AgGaS₂, AgGaSe₂, and AgGaTe₂, and (b) for AgInS₂, AgInSe₂, and AgInTe₂ at 0 GPa and 3 GPa.

Table S5. Calculated group velocities of transverse acoustic (TA) and longitudinal acoustic (LA) phonons around the Γ point for two representative pressures.

	Pressure	Γ -X			Γ -Z		
		v_{TA1} (m/s)	v_{TA2} (m/s)	v_{LA} (m/s)	v_{TA1} (m/s)	v_{TA1} (m/s)	v_{LA} (m/s)
AgAlS ₂	0 GPa	2062	2581	4830	2062	2062	4625
	3 GPa	1510	2312	5117	1510	1510	4793
	$(v_{3\text{GPa}}-v_{0\text{GPa}})/v_{0\text{GPa}}$ (%)	-26.75	-10.43	5.94	-26.75	-26.75	3.64
AgAlSe ₂	0 GPa	1775	1962	3990	1775	1775	3767
	3 GPa	1360	1825	4082	1360	1360	3841
	$(v_{3\text{GPa}}-v_{0\text{GPa}})/v_{0\text{GPa}}$ (%)	-23.42	-6.98	2.31	-23.42	-23.42	1.98
AgAlTe ₂	0 GPa	1629	1665	3456	1629	1629	3357
	3 GPa	1482	1562	3702	1482	1482	3570
	$(v_{3\text{GPa}}-v_{0\text{GPa}})/v_{0\text{GPa}}$ (%)	-9.07	-6.17	7.11	-9.07	-9.07	6.33
AgGaS ₂	0 GPa	1996	2257	4371	1996	1996	4175
	3 GPa	1591	2119	4614	1591	1591	4375
	$(v_{3\text{GPa}}-v_{0\text{GPa}})/v_{0\text{GPa}}$ (%)	-20.29	-6.12	5.55	-20.29	-20.29	4.79
AgGaSe ₂	0 GPa	1684	1901	3738	1684	1684	3573
	3 GPa	1222	1653	4009	1222	1222	3702
	$(v_{3\text{GPa}}-v_{0\text{GPa}})/v_{0\text{GPa}}$ (%)	-27.45	-13.07	7.25	-27.45	-27.45	3.61
AgGaTe ₂	0 GPa	1492	1591	3304	1492	1492	3187
	3 GPa	1289	1478	3470	1289	1289	3372
	$(v_{3\text{GPa}}-v_{0\text{GPa}})/v_{0\text{GPa}}$ (%)	-13.61	-7.70	5.03	-13.61	-13.61	5.80
AgInS ₂	0 GPa	1819	1830	3878	1819	1819	3788
	3 GPa	1563	1657	4086	1563	1563	3974
	$(v_{3\text{GPa}}-v_{0\text{GPa}})/v_{0\text{GPa}}$ (%)	-14.09	-9.43	5.38	-14.09	-14.09	4.91
AgInSe ₂	0 GPa	1523	1535	3318	1535	1535	3294
	3 GPa	1329	1373	3461	1373	1373	3420
	$(v_{3\text{GPa}}-v_{0\text{GPa}})/v_{0\text{GPa}}$ (%)	-12.74	-10.51	4.30	-10.51	-10.51	3.83
AgInTe ₂	0 GPa	1418	1424	2992	1418	1418	3001

3 GPa	1146	1295	3209	1146	1146	3244
$(v_{3\text{GPa}} - v_{0\text{GPa}}) / v_{0\text{GPa}}$ (%)	-19.17	-9.09	7.25	-19.17	-19.17	8.10

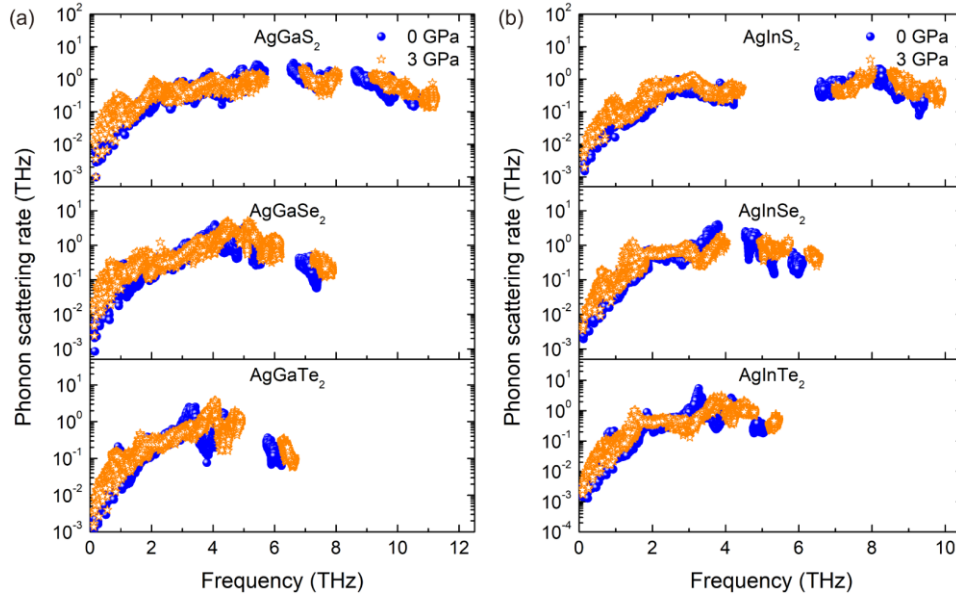


Figure S9 Phonon scattering rate for (a) AgGaS₂, AgGaSe₂, and AgGaTe₂, and (b) for AgInS₂, AgInSe₂, and AgInTe₂ at 0 GPa and 3 GPa.

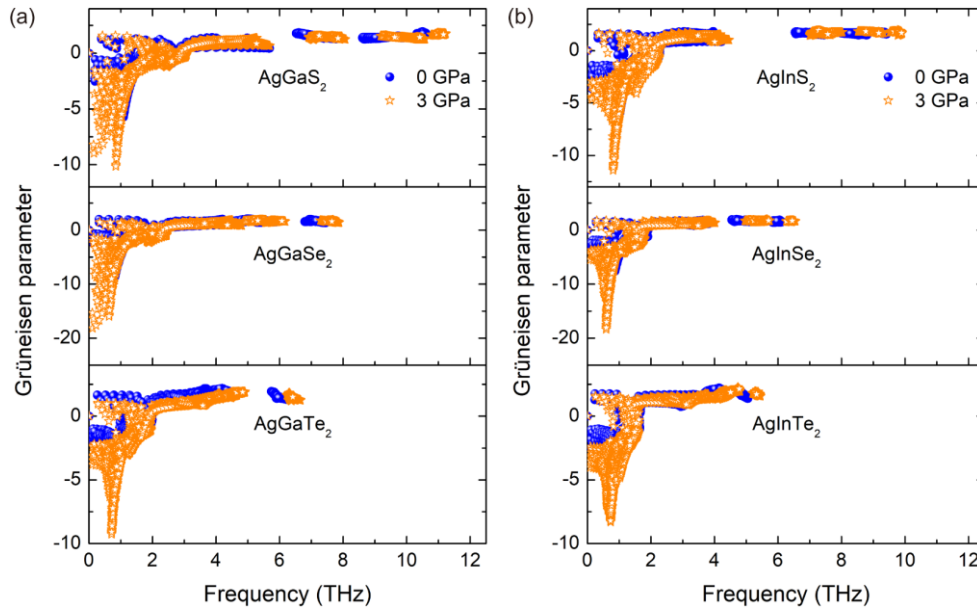


Figure S10. Grüneisen parameter for (a) AgGaS₂, AgGaSe₂, and AgGaTe₂, and (b) for AgInS₂, AgInSe₂, and AgInTe₂ at 0 GPa and 3 GPa.

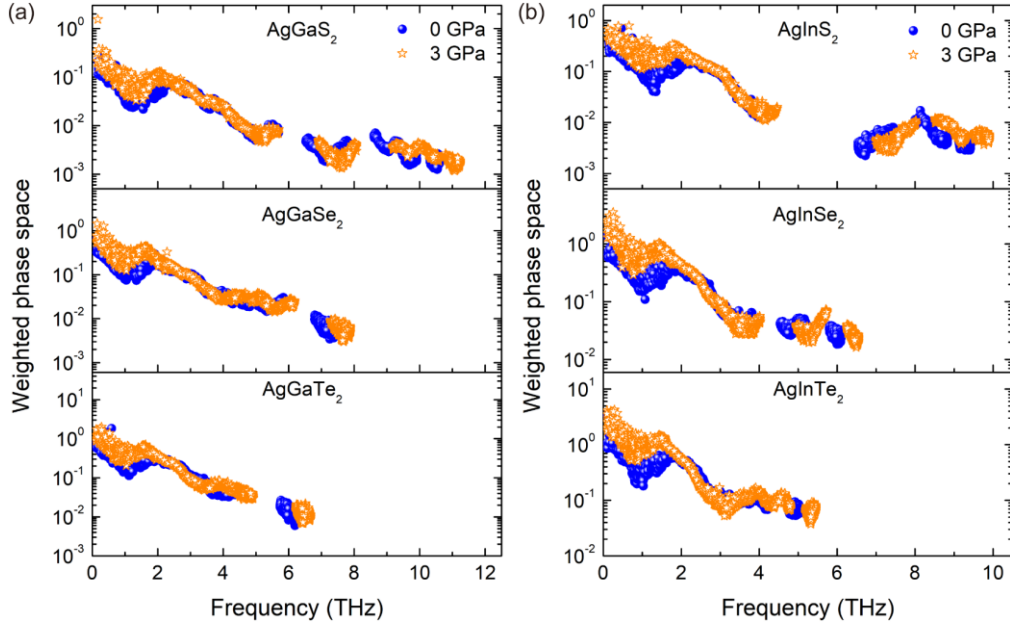


Figure S11. Weighted scattering phase space for (a) AgGaS₂, AgGaSe₂, and AgGaTe₂, and (b) for AgInS₂, AgInSe₂, and AgInTe₂ at 0 GPa and 3 GPa.

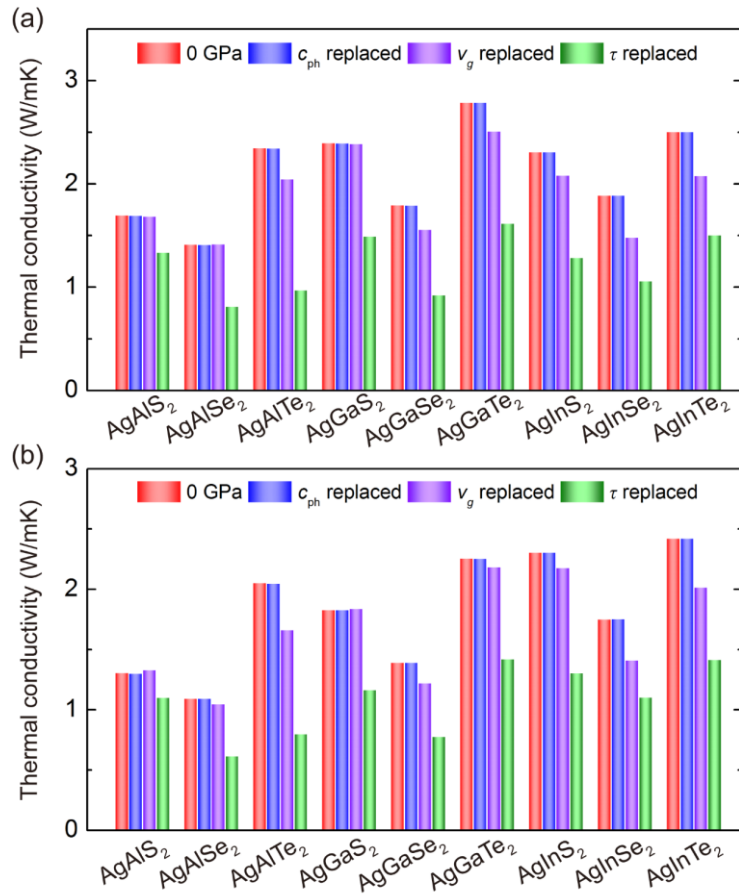


Figure S12. Cross-calculated thermal conductivity along the (a) a/b and (b) c axis with phonon specific heat c_{ph} , group velocity v_g , and relaxation time τ replaced with high-pressure values.

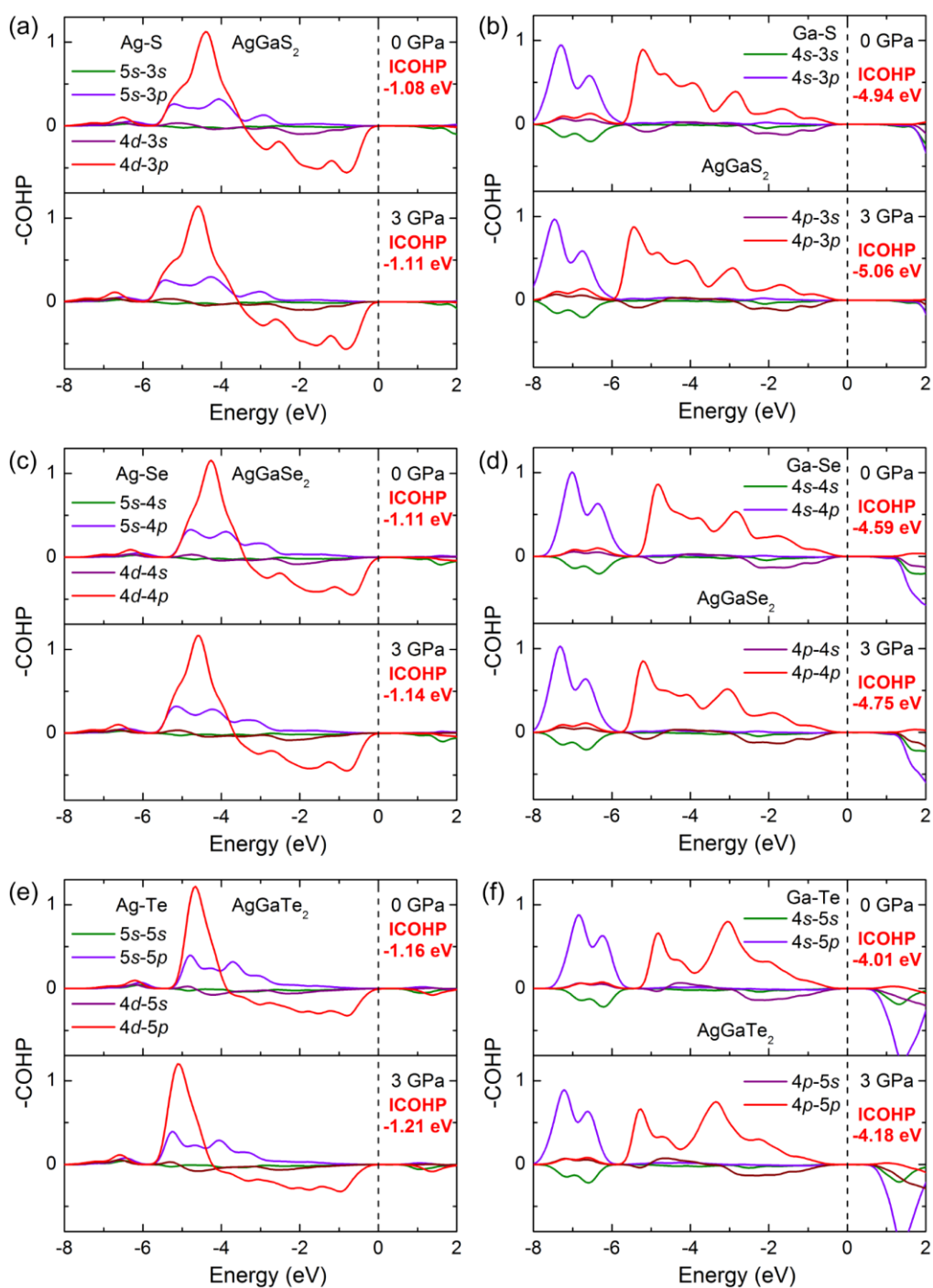


Figure S13. The calculated COHP for the Ag-Y and Ga-Y bonds of AgGaS₂, AgGaSe₂, and AgGaTe₂ at 0 GPa and 3 GPa. (a) Ag-S, (b) Ga-S, (c) Ag-Se, (d) Ga-Se, (e) Ag-Te, and (f) Ga-Te.

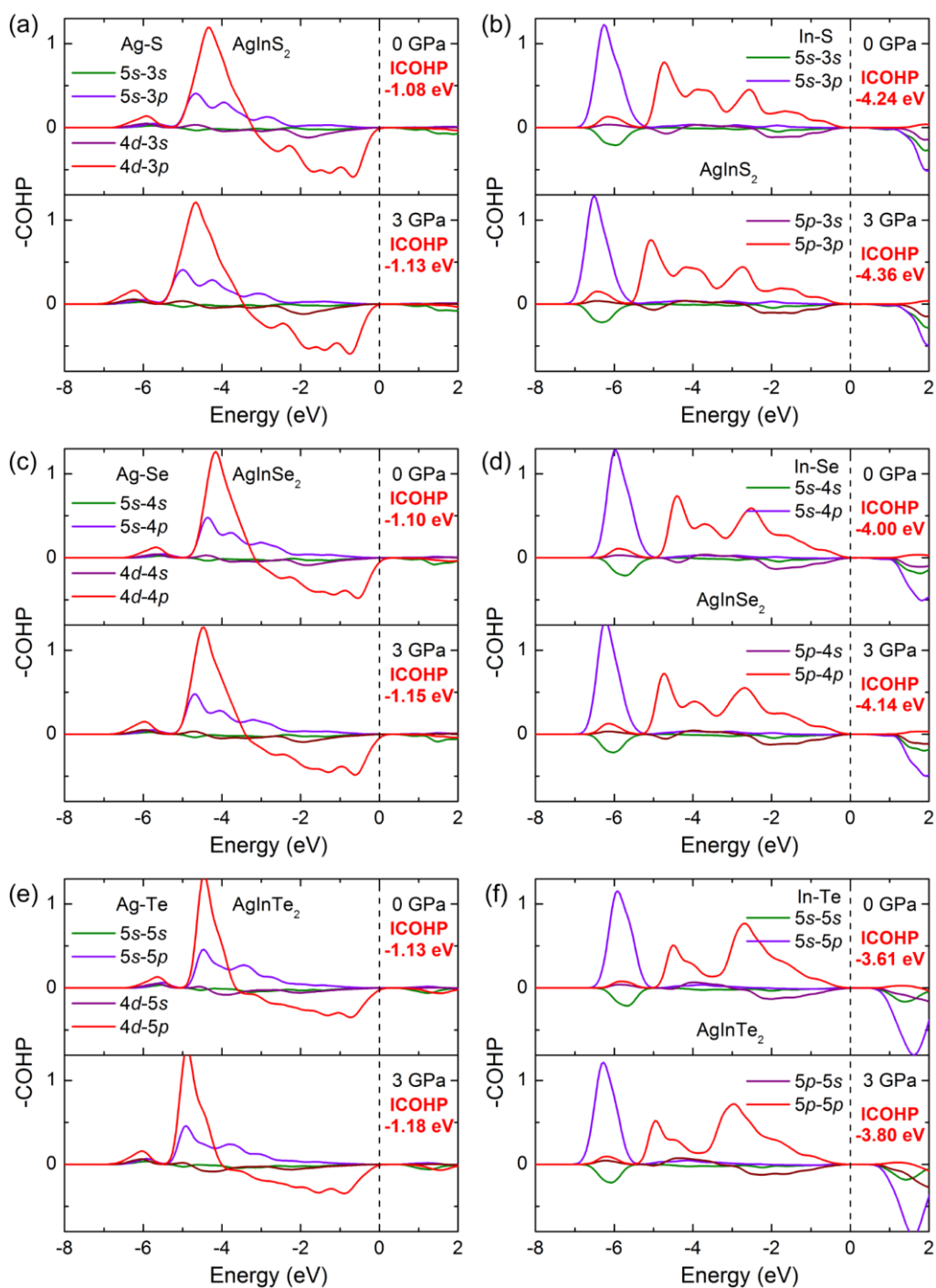


Figure S14. The calculated COHP for the Ag-Y and In-Y bonds of AgInS₂, AgInSe₂, and AgInTe₂ at 0 GPa and 3 GPa. (a) Ag-S, (b) In-S, (c) Ag-Se, (d) In-Se, (e) Ag-Te, and (f) In-Te.

Table S6. The transferred and shared electrons between atoms in AgXY_2 ($X = \text{Al, Ga, In; Y = S, Se, Te}$).

	Pressure	Transferred electron e			Shared electron e	
		Ag	X^{III}	Y^{VI}	Ag- Y^{VI}	X^{III} - Y^{VI}
AgAlS ₂	0 GPa	0.424	1.102	-0.763	0.884	1.002
	3 GPa	0.438	1.114	-0.776	0.926	1.016
AgAlSe ₂	0 GPa	0.352	0.904	-0.628	0.891	1.023
	3 GPa	0.365	0.923	-0.644	0.939	1.041
AgAlTe ₂	0 GPa	0.225	0.606	-0.415	0.971	1.055
	3 GPa	0.238	0.633	-0.435	1.031	0.082
AgGaS ₂	0 GPa	0.367	0.806	-0.587	0.904	1.070
	3 GPa	0.378	0.811	-0.594	0.944	1.097
AgGaSe ₂	0 GPa	0.290	0.638	-0.464	0.917	1.051
	3 GPa	0.297	0.643	-0.470	0.962	1.085
AgGaTe ₂	0 GPa	0.153	0.403	-0.278	1.000	1.047
	3 GPa	0.159	0.408	-0.284	1.059	1.092
AgInS ₂	0 GPa	0.370	0.893	-0.631	0.924	1.043
	3 GPa	0.380	0.898	-0.639	0.975	1.075
AgInSe ₂	0 GPa	0.302	0.737	-0.519	0.933	1.028
	3 GPa	0.308	0.742	-0.525	0.989	1.068
AgInTe ₂	0 GPa	0.178	0.520	-0.349	1.002	1.032
	3 GPa	0.184	0.524	-0.354	1.071	1.084

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